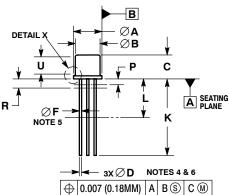
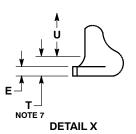


TO-18 CASE 206AA **ISSUE A** 

**DATE 21 AUG 2012** 







LEAD IDENTIFICATION DETAIL

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: INCHES.

- DIMENSION J MEASURED FROM DIAMETER A TO EDGE.
  LEAD TRUE POSITION TO BE DETERMINED AT THE GUAGE PLANE DEFINED BY DIMENSION R.
  DIMENSION F APPLIES BETWEEN DIMENSION P AND L.
- DIMENSION D APPLIES BETWEEN DIMENSION L AND K.
- BODY CONTOUR OPTIONAL WITHIN ZONE DEFINED BY DIMENSIONS A, B, AND T.

|     | MILLIMETERS |       | INCHES    |       |
|-----|-------------|-------|-----------|-------|
| DIM | MIN         | MAX   | MIN       | MAX   |
| Α   | 5.31        | 5.84  | 0.209     | 0.230 |
| В   | 4.52        | 4.95  | 0.178     | 0.195 |
| С   | 4.32        | 5.33  | 0.170     | 0.210 |
| D   | 0.41        | 0.53  | 0.016     | 0.021 |
| Е   | -           | 0.76  |           | 0.030 |
| F   | 0.41        | 0.48  | 0.016     | 0.019 |
| Н   | 0.91        | 1.17  | 0.036     | 0.046 |
| J   | 0.71        | 1.22  | 0.028     | 0.048 |
| K   | 12.70       | 19.05 | 0.500     | 0.750 |
| L   | 6.35        |       | 0.250     |       |
| M   | 45°         | BSC   | 45°       | BSC   |
| N   | 2.54 BSC    |       | 0.100 BSC |       |
| P   | -           | 1.27  |           | 0.050 |
| R   | 1.37 BSC    |       | 0.054 BSC |       |
| T   | -           | 0.76  |           | 0.030 |
| U   | 2.54        |       | 0.100     |       |

 $\emptyset$ N С

> STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR

STYLE 4: PIN 1. SOURCE 2. DRAIN 3. GATE & CASE

STYLE 7: PIN 1. ANODE 2. BASE 3. CATHODE

STYLE 10: PIN 1. BASE 2. EMITTER 3. BASE

STYLE 2: PIN 1. SOURCE, SUBSTRATE & CASE 2. GATE

3. DRAIN

STYLE 5: PIN 1. EMITTER 2. BASE 1 3 BASE 2

STYLE 8: PIN 1. GATE 2. ANODE 1

STYLE 11:
PIN 1. DRAIN
2. GATE
3. SOURCE, SUBSTRATE

3. ANODE 2

PIN 1. CATHODE 2. GATE 3. ANODE

STYLE 6:

STYLE 3: PIN 1. SOURCE

2. DRAIN 3. GATE

STYLE 9: PIN 1. ANODE 2 2. ANODE 1 3. GATE

(CONNECTED TO CASE)

STYLE 12: PIN 1. SOURCE 2. GATE 3. DRAIN (CASE)

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|------------------|--------------|--|-------------|
| DESCRIPTION:     | TO-18 3-LEAD | •  | PAGE 1 OF 1 |

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